

EAST - [resistor.wsp.1]

File View Edit Tools Window Help

☐ Drafts  
☒ Pending  
☒ Active  
☐ Failed  
☐ Saved

L1: (141563) magnetic.clm.  
 L2: (933) 1 and (MTJ or (magnetic adj2 junction))  
 L3: (39) 2 and ((implant\$3 or diffus\$3 or dop\$3) near10 (magnetic  
 L4: (95) 2 and ((implant\$3 or diffus\$3 or dop\$3) near10 (magnetic  
 L5: (68) 2 and (implant\$3 or diffus\$3 or dop\$3).clm.  
 L6: (45) 5 and (implant\$3.clm. or doping.clm. or diffusion.clm.)  
 L7: (30) 6 and (magnetic adj2 (layer\$1 or film\$1)).clm.  
 L8: (4049) 1 and (MTJ or (magnetic adj2 junction) or (magnetic adj  
 L9: (29) 8 and (diffusion near3 (component\$1 or element\$1))  
 L10: (54) 8 and (diffusion near3 (component\$1 or element\$1 or atom  
 L11: (8) 10 and (diffusion near3 (component\$1 or element\$1 or atom

(0) ("(thinadjfilm)nearresistor").PN.  
 (0) ("(thinadjfilm)nearresistor").PN.  
 (150130) thin adj film  
 (14857) (thin adj film) and resistor  
 (2054) ((thin adj film) and resistor) and ((thin adj film) near res

6 and (magnetic adj2 (layer\$1 or film\$1)).clm.

365/98  
 365/200  
 365/173  
 365/210  
 365/158/  
 365/173  
 257/E43.00  
 365/200  
 365/200  
 365/158  
 257/E27.00  
 5  
 257/295  
 360/324.2  
 257/E45.00  
 365/200  
 365/171  
 365/158/

	U	I	P	T	P	Document ID	Issue Dat	Pages	Title	Current CR	Current CR	Retrieval	Inventor	S	C	J	
1	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 20040109339	20040610	13	MRAM memories utilizing	365/98			Tsang, David	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>
2	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 20040095813	20040520	46	Semiconductor	365/200			Hosotani, Keiji	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>
3	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 20040076036	20040422	25	integrated circuit devi	365/173			Heide, Carsten	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>
4	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 20040008556	20040115	33	Magnetic memory device	365/210	365/158/ 365/173		Hidaka, Hideto	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>
5	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 20030911	20030911	11	Memory device reading	438/689	257/E43.00		Hwang, Jeng H. et al.	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>
6	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 20030170985	20030605	27	Etching methods for a	365/200	6		Asao, Yoshiaki	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>
7	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 20030103393	20030508	25	magnetic memory cell st	365/200			Asao, Yoshiaki	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>
8	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 20030086313	20030424	13	and method for manufact	365/200			Kim, Dong-wook et al.	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>
9	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 20030076707	20030403	17	using SOI substrate and	257/295	5		Ramesh, Ramamoorthy et al.	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>
10	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 20030062553	20011115	21	Epitaxial template and	360/324.2	257/E45.00		ABRAHAM, DAVID	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>
11	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 20010040778	20010927	5	barrier for the integra	365/200	1:		WILLIAM et al.	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>
12	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 20010024388	20040706	32	LIMITING	365/171	365/158/		Schwarzl, Siegfried	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>
13	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 6760251			MAGNETORESISTIVE ELECTR				Hidaka, Hideto	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>
	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>				Magnetoresistive					<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>
	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>				element and use thereof					<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>
	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>				Memory device reading					<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>